

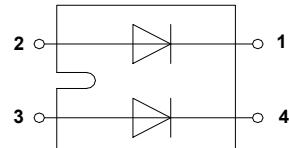
# JU101K2/06

## Description

- 1) Low forward voltage drop
- 2) Two fully independent diodes
- 3) Fully insulated package
- 4) Easy to use and parallel
- 5) Industry standard outline
- 6) Designed and qualified for industrial level



SOT-227



Symbol

## Typical Application

Optimized for power conversion: welding and industrial SMPS applications

## Absolute Maximum Ratings (Packaged into SOT-227, unless otherwise specified, $T_{CASE}=25^{\circ}\text{C}$ )

Parameter	Test Conditions	Symbol	Values		Unit
Junction temperature range		$T_J$	-40	150	$^{\circ}\text{C}$
Storage temperature range		$T_{STG}$	-40	150	$^{\circ}\text{C}$
Repetitive peak reverse voltage	$T_J=25^{\circ}\text{C}$	$V_{RRM}$	600		V
Non-repetitive peak reverse voltage	$T_J=25^{\circ}\text{C}$	$V_{RSM}$	600		V
Average forward current	$T_C=50^{\circ}\text{C}$ , per diode	$I_{F(AV)}$	100		A
Peak on-state surge current	$t_P=10\text{ms}, \sin 180^{\circ}, T_J=25^{\circ}\text{C}$	$I_{FSM}$	1000		A
$I^2t$ value	$t_P=10\text{ms}, \sin 180^{\circ}, T_J=25^{\circ}\text{C}$	$I^2t$	5000		$\text{A}^2\text{s}$
Isolation voltage	A.C 50Hz(1s/1min)	$V_{iso}$	3000/2500		V

## Electrical Characteristics (Packaged into SOT-227, unless otherwise specified, $T_{CASE}=25^{\circ}\text{C}$ )

Parameter	Test Conditions	Symbol	Values			Unit
			Min.	Typ.	Max.	
Forward voltage	$I_F=100\text{A}, T_J=25^{\circ}\text{C}$	$V_F$	-	1.45	1.80	V
Reverse leakage current	$V_R=V_{RRM}, T_J=25^{\circ}\text{C}$	$I_R$	-	-	0.01	mA
	$V_R=V_{RRM}, T_J=150^{\circ}\text{C}$		-	-	20	mA
Maximum reverse recovery time	$I_F=100\text{A}, V_R=300\text{V}, -di/dt=200\text{A}/\mu\text{s}, T_J=25^{\circ}\text{C}$	$t_{rr}$	-	150	250	ns



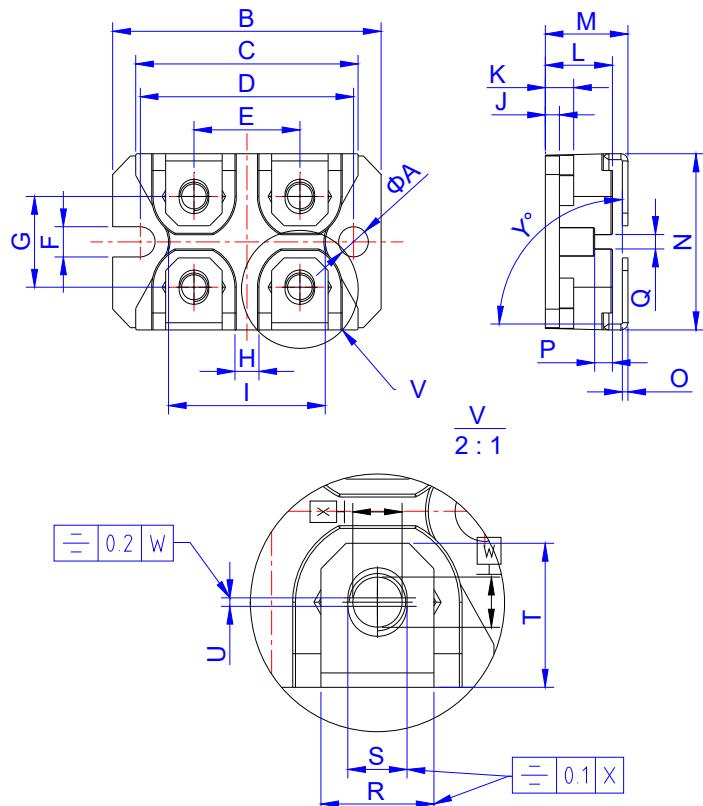
## Rectifier Diode Module

**Thermal Characteristics**(Packaged into SOT-227, unless otherwise specified,  $T_{CASE}=25^{\circ}\text{C}$ )

Parameter	Test Conditions	Symbol	Values			Unit
			Min.	Typ.	Max.	
Junction to case(per diode)		$R_{th(j-c)}$	-	-	0.5	
Case to heatsink		$R_{th(c-s)}$	-	0.125	-	°C/W
Weight			-	35	-	g
Mounting torque	Base plate to heatsink screw M4	M	1.0	-	1.5	N·m
	Electrode to terminal screw M4		1.0	-	1.5	N·m
Case style			SOT-227			

### Ordering Information

<u>J</u>	<u>U</u>	<u>101</u>	<u>K2</u>	<u>/06</u>	
JieJie Semiconductor Co., Ltd.					<u>06: <math>V_{RRM} \geq 600V</math></u>
		<u><math>I_{F(AV)}=100A</math></u>			<u>Dual circuit module</u>

**Mechanical Characteristics**


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.1	4.2	4.4	0.161	0.165	0.173
B	38.0	38.2	38.4	1.496	1.504	1.512
C	31.1	31.5	31.9	1.224	1.240	1.256
D	30.1	30.2	30.3	1.185	1.189	1.193
E	14.8	15.0	15.2	0.583	0.591	0.598
F	4.1	4.2	4.4	0.161	0.165	0.173
G	12.3	12.5	12.7	0.484	0.492	0.500
H		4.2			0.165	
I		21.6			0.850	
J		2			0.079	
K		4.05			0.159	
L		9.5			0.374	
M	11.6	11.9	12.2	0.457	0.469	0.480
N	24.7	25.1	25.5	0.972	0.988	1.004
O		0.8			0.031	
P		2.6			0.102	
Q		1.7			0.067	
R		8			0.315	
S	4.1	4.2	4.4	0.161	0.165	0.173
T		10.7			0.421	
U		1			0.039	
Y	89°	90°	91°	89°	90°	91°

**Technical requirements:**

1. Unmarked tolerances of dimension are performed in accordance with GB/T 1804-2000 Level C
2. Unmarked tolerances of form and position are performed in accordance with GB/T 1184-1996 Level L

**Package Information-SOT-227**

OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON (PCS)
TUBE	8	80	160

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